

## **isc Silicon NPN Power Transistor**

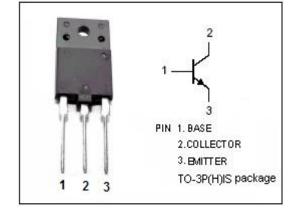
# **BU2522AX**

#### **DESCRIPTION**

- · Collector-Emitter Sustaining Voltage-
  - : V<sub>CEO(SUS)</sub>= 800V (Min)
- · High Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### **APPLICATIONS**

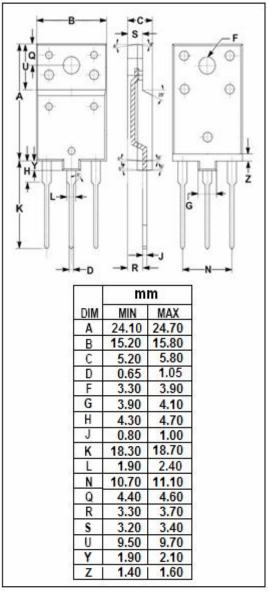
 Designed for use in horizontal deflection circuits of pc monitors.



### ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CES</sub>	Collector- Emitter Voltage(V <sub>BE</sub> = 0)	1500	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	800	V	
V <sub>EBO</sub>	Emitter-Base Voltage	7.5	V	
Ic	Collector Current- Continuous	10	А	
Ісм	Collector Current-Peak	25	Α	
lв	Base Current- Continuous	6	А	
I <sub>BM</sub>	Base Current-Peak	9	Α	
Pc	Collector Power Dissipation @ T <sub>c</sub> =25°C	45	W	
Тл	Junction Temperature	150	$^{\circ}$	
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C	

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance,Junction to Case	2.8	°C/W





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#### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

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SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT				
V <sub>CEO(SUS)</sub>	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 50mA; I <sub>B</sub> = 0	800			V				
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 1mA; I <sub>C</sub> = 0	7.5			V				
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 6A; I <sub>B</sub> = 1.2A			5.0	V				
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 6A; I <sub>B</sub> = 1.2A			1.3	V				
I <sub>CES</sub>	Collector Cutoff Current	V <sub>CE</sub> = 1500V; V <sub>BE</sub> = 0 V <sub>CE</sub> = 1500V; V <sub>BE</sub> = 0; T <sub>C</sub> =125℃			0.25 2.0	mA				
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 7.5V; I <sub>C</sub> = 0			0.25	mA				
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 1A; V <sub>CE</sub> = 5V		10						
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 6A; V <sub>CE</sub> = 5V	5		8					

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